



CHENMKO ENTERPRISE CO.,LTD

SURFACE MOUNT GLASS PASSIVATED

SUPER FAST SILICON RECTIFIER

VOLTAGE RANGE 50 - 1000 Volts CURRENT 2.0 Amperes

USM21PT

THRU

USM28PT

Lead free devices

FEATURES

- * For surface mounted applications
- * Low profile package
- * Built-in strain relief
- * Superfast recovery times for high efficiency
- * Metallurgically bonded construction
- * Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- * Glass passivated junction
- * High temperature soldering guaranteed : 260°C/10 seconds at terminals

MECHANICAL DATA

Case: JEDEC SMA molded plastic

Terminals: Solder plated, solderable per MIL-STD-750, Method 2026

Polarity: Indicated by cathode band

Weight: 0.002 ounces, 0.064 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

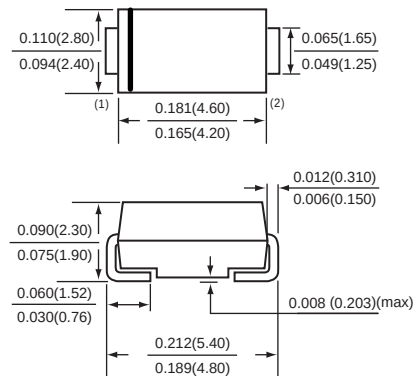
Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%.



SMA



Dimensions in inches and (millimeters)

SMA

MAXIMUM RATINGS (At $T_A = 25^\circ\text{C}$ unless otherwise noted)

RATINGS	SYMBOL	USM21PT	USM22PT	USM23PT	USM24PT	USM25PT	USM26PT	USM27PT	USM28PT	UNITS
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	300	400	600	800	1000	Volts
Maximum RMS Voltage	VRMS	35	70	140	210	280	420	560	700	Volts
Maximum DC Blocking Voltage	VDC	50	100	200	300	400	600	800	1000	Volts
Maximum Average Forward Rectified Current TL = 100°C	Io	2.0								Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	IFSM	50								Amps
Typical Junction Capacitance (Note 1)	Cj	30					20			pF
Operating and Storage Temperature Range	TJ, TSTG	-65 to +150								°C

ELECTRICAL CHARACTERISTICS (At $T_A = 25^\circ\text{C}$ unless otherwise noted)

CHARACTERISTICS		SYMBOL	USM21PT	USM22PT	USM23PT	USM24PT	USM25PT	USM26PT	USM27PT	USM28PT	UNITS
Maximum Instantaneous Forward Voltage at 2.0 A DC		V _F	0.95				1.27	1.75			Volts
Maximum DC Reverse Current	@ TA = 25°C	I _R	5.0								uAmps
at Rated DC Blocking Voltage	@ TA = 100°C		100								uAmps
Maximum Reverse Recovery Time (Note 2)		t _{rr}	35					45			nSec

NOTES : 1. Measured at 1.0 MHz and applied reverse voltage of 4.0 volts
2. Test Conditions : $I_F = 0.5\text{ A}$, $I_R = -1.0\text{ A}$, $I_{RR} = -0.25\text{ A}$

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RATING CHARACTERISTIC CURVES (USM21PT THRU USM28PT)

FIG. 1 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

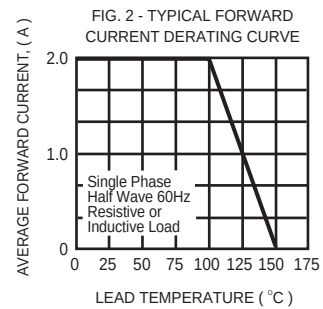
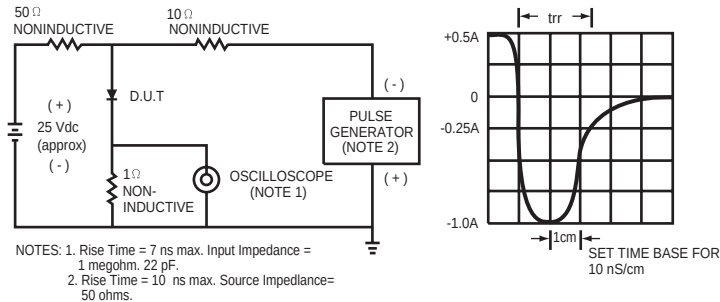


FIG. 3 - TYPICAL REVERSE CHARACTERISTICS

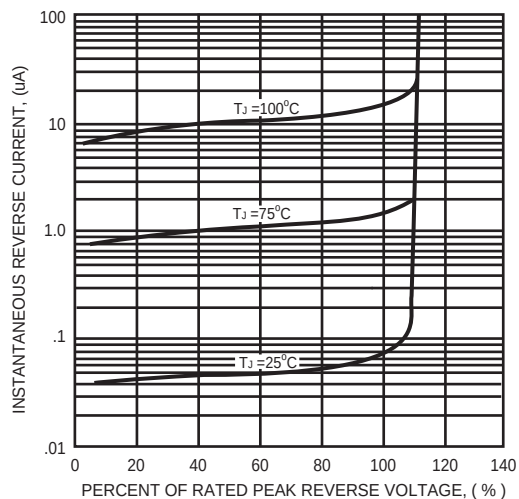


FIG. 4 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

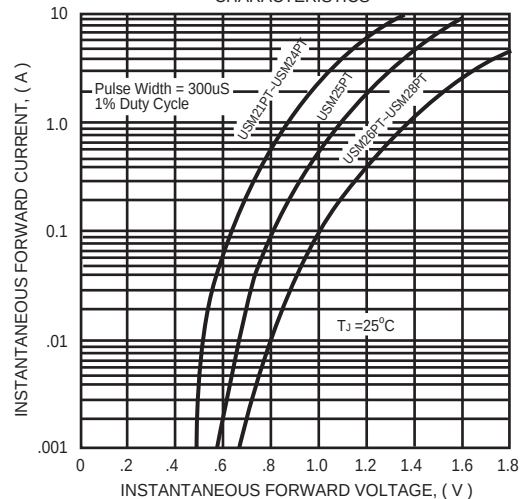


FIG. 5 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

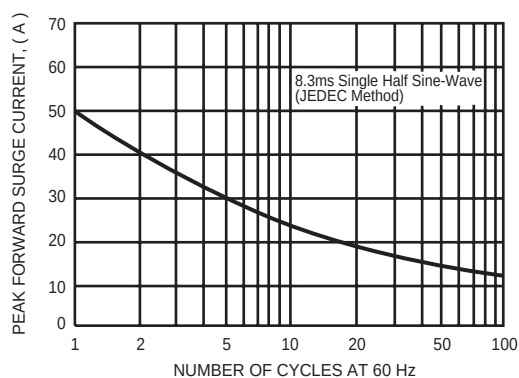


FIG. 6 - TYPICAL JUNCTION CAPACITANCE

